



General Multilayer Ceramic Capacitors



MLCC is an electronic part that temporarily stores an electrical charge and the most prevalent type of capacitor today. New technologies have enabled the MLCC manufacturers to follow the trend dictated by smaller and smaller electronic devices such as Cellular telephones, Computers, DSC, DVC

General Features

- Miniature Size
- Wide Capacitance and Voltage Range
- Tape & Reel for Surface Mount Assembly
- Low ESR

Applications

- General Electronic Circuit

Part Numbering

CL	<u>10</u>	<u>B</u>	104	K	<u>B</u>	<u>8</u>	N	N	N	<u>C</u>
Ú	2	8	4	6	6	V	8	9	1	(i)

- Samsung Multilayer Ceramic Capacitor
- 2 Size(mm)
- **3** Capacitance Temperature Characteristic
- 4 Nominal Capacitance
- **6** Capacitance Tolerance
- 6 Rated Voltage

- Thickness Option
- Product & Plating Method
- Samsung Control Code
- Reserved For Future Use
- Packaging Type

1 Samsung Multilayer Ceramic Capacitor

2 SIZE(mm)

Code	EIA CODE	Size(mm)
03	0201	0.6 × 0.3
05	0402	1.0 × 0.5
10	0603	1.6 × 0.8
21	0805	2.0 × 1.25
31	1206	3.2 × 1.6
32	1210	3.2 × 2.5
43	1812	4.5 × 3.2
55	2220	5.7 × 5.0





3 CAPACITANCE TEMPERATURE CHARACTERISTIC

Code		Temperature Characteristics				
С		COG	C△	0 ± 30 (ppm/ °C)		
Р		P2H	P△	-150 ± 60		
R		R2H	R△	-220 ± 60		
S	Class	S2H	S△	-330 ± 60	-55 ~ +125℃	
Т		T2H	T△	-470 ± 60		
U		U2J	U△	-750 ± 60		
L		S2L	S△	+350 ~ -1000		
Α		X5R	X5R	±15%	-55 ~ +85℃	
В	Class II	X7R	X7R	±15%	-55 ~ +125℃	
X	UIASS II	X6S	X6S	±22%	-55 ~ +105℃	
F		Y5V	Y5V	+22 ~ -82%	-30 ~ +85℃	

*** Temperature Characteristic**

Temperature Characteristics	Below 2.0pF	2.2 ~ 3.9pF	Above 4.0pF	Above 10pF
СФ	C0G	C0G	C0G	C0G
₽Δ	-	P2J	P2H	P2H
R∆	-	R2J	R2H	R2H
SΔ	-	S2J	S2H	S2H
TΔ	-	T2J	T2H	T2H
UΔ	-	U2J	U2J	U2J

 $J:\pm 120 PPM/{}^{\circlearrowright},\, H:\pm 60 PPM/{}^{\circlearrowleft},\, G:\pm 30 PPM/{}^{\circlearrowleft}$

4 NOMINAL CAPACITANCE

Nominal capacitance is identified by 3 digits.

The first and second digits identify the first and second significant figures of the capacitance.

The third digit identifies the multiplier. 'R' identifies a decimal point.

Example

Code	Nominal Capacitance
1R5	1.5pF
103	10,000pF, 10nF, 0.01 μF
104	100,000pF, 100nF, 0.1 μ F





O CAPACITANCE TOLERANCE

Code	Tolerance	Nominal Capacitance
Α	±0.05pF	
В	±0.1pF	
С	±0.25pF	Less than 10pF (Including 10pF)
D	± 0.5pF	(morading Topi)
F	±1pF	
F	±1%	
G	±2%	
J	±5%	More then 10pF
K	±10%	More than 10pF
М	±20%	
Z	+80, -20%	

6 RATED VOLTAGE

Code	Rated Voltage	Code	Rated Voltage
R	4.0V	D	200 V
Q	6.3V	E	250 V
Р	10V	G	500 V
O	16V	Н	630 V
Α	25V	I	1,000V
L	35V	J	2,000V
В	50V	К	3,000V
С	100V		





THICKNESS OPTION

Size	Code	Thickness(T)	Size	Code	Thickness(T)
0201(0603)	3	0.30±0.03		F	1.25±0.20
0402(1005)	5	0.50±0.05		н	1.6±0.20
0603(1608)	8	0.80±0.10	1812(4532)	I	2.0±0.20
	Α	0.65±0.10		J	2.5±0.20
	С	0.85±0.10		L	3.2±0.30
0805(2012)	F	1.25±0.10		F	1.25±0.20
	Q	1.25±0.15		н	1.6±0.20
	Υ	1.25±0.20	2220(5750)	ı	2.0±0.20
	С	0.85±0.15		J	2.5±0.20
1206(3216)	F	1.25±0.15		L	3.2±0.30
	Н	1.6±0.20			
	F	1.25±0.20			
	Н	1.6±0.20			
1210(3225)	I	2.0±0.20			
	J	2.5±0.20			
	V	2.5±0.30			

PRODUCT & PLATING METHOD

Code	Electrode	Termination	Plating Type
Α	Pd	Ag	Sn_100%
N	Ni	Cu	Sn_100%
G	Cu	Cu	Sn_100%

SAMSUNG CONTROL CODE

Code	Description of the code	Code	Description of the code
Α	Array (2-element)	N	Normal
В	Array (4-element)	Р	Automotive
С	High - Q	L	LICC





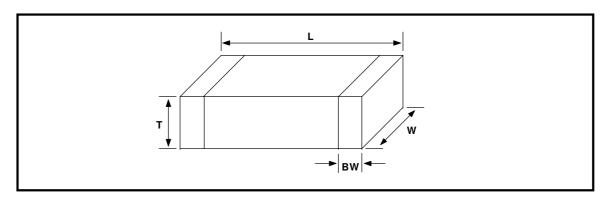
TRESERVED FOR FUTURE USE

Code	Description of the code
N	Reserved for future use

1 PACKAGING TYPE

Code	Packaging Type	Code	Packaging Type
В	Bulk	F	Embossing 13" (10,000EA)
Р	Bulk Case	L	Paper 13" (15,000EA)
С	Paper 7"	0	Paper 10"
D	Paper 13" (10,000EA)	S	Embossing 10"
Е	Embossing 7"		

APPEARANCE AND DIMENSION



CODE	EIA CODE		DIMENSION (mm)								
CODE		L	W	T (MAX)	BW						
03	0201	0.6 ± 0.03	0.3 ± 0.03	0.33	0.15 ± 0.05						
05	0402	1.0 ± 0.05	0.5 ± 0.05	0.55	0.2 +0.15/-0.1						
10	0603	1.6 ± 0.1	0.8 ± 0.1	0.9	0.3 ± 0.2						
21	0805	2.0 ± 0.1	1.25 ± 0.1	1.35	0.5 +0.2/-0.3						
04	1206	3.2 ± 0.15	1.6 ± 0.15	1.40	0.5 +0.2/-0.3						
31		3.2 ± 0.2	1.6 ± 0.2	1.8	0.5 +0.3/-0.3						
20	1010	3.2 ± 0.3	2.5 ± 0.2	2.7	0.6 ± 0.2						
32	1210	3.2 ± 0.4	2.5 ± 0.3	2.8	0.6 ± 0.3						
43	1812	4.5 ± 0.4	3.2 ± 0.3	3.5	0.8 ± 0.3						
55	2220	5.7 ± 0.4	5.0 ± 0.4	3.5	1.0 ± 0.3						





NO	ITE	М	PER	FORMANCE	TEST	CONDITION			
1	Appea	rance	No Abnormal Exterior	Appearance	Through Microscope(×10)			
2	Insula Resist		10,000MΩ or 500 MΩ·μF· Rated Voltage is below 10,000MΩ or 100 MΩ·μF·	w 16V ;	Apply the Rated Voltage For 60 ~ 120 Sec.				
3	Withsta	•	No Dielectric Breakdov Mechanical Breakdowr	-	Class I : 300% of the Rated Voltage for 1~5 sec. Class II :250% of the Rated Voltage for 1~5 sec. is applied with less than 50 mA current				
					Capacitance	Frequency	Voltage		
		Class	Within the specifie	d tolerance	≤ 1,000 pF	1 Ml½ ±1 0%			
	Capacita	I			>1,000 pF	1 kHz ±1 0%	0.5 ~ 5 Vrms		
4	nce				Capacitance	Frequency	Voltage		
		Class	Within the specifi	ed tolerance	≤ 10 μF	1 kHz ±1 0%	1.0±0.2Vrms		
		П	·		>10 <i>µ</i> F	120Hz±20%	0.5±0.1 Vrms		
			Capacitance ≥ 30pF :	Q ≥ 1 000	Capacitance	Frequency	Voltage		
5	Q	Class		: Q ≥ 400 +20C	≤ 1,000 pF	1 MHz ±1 0%	_		
	I		(C	: Capacitance)	>1,000 pF	1 kHz ±1 0%	0.5 ~ 5 Vrms		
			1. Characteristic : A()	X5R), B(X7R), X(X6S)	Capacitance	Frequency	Voltage		
			Rated Voltage	Spec	∫ ≤ 10 μF	1 kHz ±1 0%	1.0±0.2Vrms		
			≥ 25V	0.025 max	>1 0 µF	120Hz±20%	0.5±0.1 Vrms		
			16V	0.035 max					
			10V	0.05 max					
			6.3V	0.05 max/ 0.10max*1	*1. 0201 C≥0.022uF, 0	402 C≥0.22uF,	0603 C≥2.2uF,		
			2. Characteristic : F(Y5V)	0805 C≥4.7uF, 1200 1812 C≥47uF, 2220 All Low Profile Capa	C≥100uF, acitors (P.16).) C≥22uF,		
6	Tan δ	Class	Rated Voltage	Spec	*2 0603 C≥0.47uF, 08				
0	I all 0	П	50V	0.05 max, 0.07max*2	*3. 0402 C≥0.033uF, 00		F		
			35V	0.07 max	All 0805, 1206 size *4 1210 C>6.8uF	, 1210 C≥ 6.8u	F		
			25V	0.05 max/ 0.07 max* ³ / 0.09max* ⁴	*5 0402 C≥0.22uF				
			16V	0.09 max/ 0.125max*5	0 All 1012 Size				
			10V	0.125 max/ 0.16max*6					
			6.3V	0.16max	_				
			6.3V	0.16max					





NO	ITE	M	F	PERFORI	MANCE	TEST CONDITION													
						Capacitance s	shall be measured by the steps												
					Temp. Coefficient		following table.												
			Characteris	stics	remp. Coeindent (PPM/℃)	Step	Temp.(℃)												
			COG		0 ± 30	1	25 ± 2												
			PH		-150 ± 60	2	Min. operating temp. ± 2												
		Class	RH		-220 ± 60														
		I	SH		-330 ± 60	3	25 ± 2												
			TH		-470 ± 60	4	Max. operating temp ± 2												
			UL		-750 ± 120	5	25 ± 2												
			SL		+350 ~ -1000	(1) Class I	Occiffed to the little control to the first												
	Temperature						Coefficient shall be calculated from												
7	Characteristics					the formula a													
,	of Capacitance						$nt = \frac{C2 - C1}{C1 \times \triangle T} \times 10^6 \text{ [ppm/°C]}$												
							ance at step 3												
			Characteristics Capacitance Change			C2: Capacita													
		Characteristics with No Bia				△T: 60 °C (=8	35 ℃-25 ℃)												
		Class II	A(X5R B(X7F	R)/ R)	± 15%	(2) CLASS II	(2) CLASS II												
		_	X(X6S	S)	± 22%	Capacitance (Change shall be calculated from the												
			F(Y5V	′)	+22% ~ -82%	formula as be	elow.												
						$\triangle C = \frac{C2 - C^2}{C}$	C1 × 100(%)												
						C1; Capacita	ance at step 3												
						C2: Capacita	ance at step 2 or 4												
						Apply 500g.f	* Pressure for 10 \pm 1 sec.												
						* 200g.f for 0	201 case size.												
	Adhesive	Strength	No Indication	n Of Peeli	ing Shall Occur On The														
8	of Termi	•	Terminal Ele		ing onai occur on the														
							500g.f												
		Apperance	No mechan	nical dam	age shall occur.	Bending limit													
						Test speed ;	1.0mm/SEC. board at the limit point in 5 sec.,												
			Characte	ristics	Capacitance Change		e capacitance.												
						inen measur	e capacitance.												
					Within \pm 5% or \pm 0.														
			Class	: I	5 pF whichever is		20 ∡												
	Bending				larger	50													
9	Strength			A(X5R)/		J 30 4													
		Capacitance		B(X7R)/	Within ± 12.5%		▼ V												
				X(X6S)															
				,,		│ 	Bending limit												
					Class II			45±1	45±1										
														G	E/V5V				
																	F(Y5V)	Within ±30%	





NO	IT	EM		PERF	ORMANCE	TEST CONDITION				
			More Than	75% of th	ne terminal surface is to	Solder	Sn-3Ag-0.5	Cu 63Sn-37Pb		
			be soldered newly, So metal part does not			Solder	a : 0~	2620		
			come out	or dissolve		Temp.	Temp. 245±5 ℃ 235±5 ℃			
10	Solde	erability		/ / _		Flux	Flux RMA Type			
			 /	′ /	/ //	Dip Time	3±0.3 sec	5±0.5 sec.		
						Pre-heating at 80~120℃ for 10~30 sec.				
		Apperance	No mecha	anical dam	age shall occur.	Solder Ter	Solder Temperature : 270±5℃			
			Charac	teristics	Capacitance Change	Dip Time : 10±1 sec.				
					Within ±2.5% or			fully immersed and		
			Clas	s I	±0.25 pF whichever is	preheated as below:				
		Capacitance			larger	0750	TEMP (%)	TIME (0.5.0.)		
		Capacitario		A(X5R)/	Within ±7.5%	STEP	TEMP.(℃)	TIME(SEC.)		
			Class II	B(X7R)		1	80~100	60		
				X(X6S)	Within ±15%	2	150~180	60		
11	Resistance to			F	Within ±20%	Leave the capacitor in ambient condition for				
	Soldering heat	Q	Capacitar	nce ≥30pF	: Q≥ 1000	specified time* before measurement * 24 ± 2 hours (Class I)				
		(Class I)		<30 pF	: Q≥ 400+20×C		nours (Class I			
				(C: Capacitance)			iouis (Glass II)		
		Tan δ (Class $ \mathbb{I} $)	Within the	e specified	initial value					
		Insulation								
		Resistance	Within the	Within the specified initial value						
		Withstanding		Within the specified initial value						
		Voltage	Within the	e specified	initial value					
		A n n a ara n a a	No moob		aga aball agair					
		Appearance	No mech	anicai uani	age shall occur.					
			Charact	teristics	Capacitance Change					
					Within ±2.5% or		itor shall be su	•		
			Clas	s I	±0.25 pF whichever is	Harmonic Motion having a total amplitude of 1.5mm changing frequency from 10Hz to 55H				
		Capacitance			larger		to 10Hz In 1 m	-		
				A(X5R)/ B(X7R)	Within ±5%					
12	Vibration		Class	X(X6S)	Within ±10%	Repeat thi	s for 2hours ea	ch in 3 mutually		
	Test		"	F(Y5V)	Within ±20%	perpendicu	lar directions			
		Q		1(134)	Within ±20%					
		(Class I)	Within the	e specified	initial value					
		Tan δ	1							
		(Class II)	Within the	e specified	initial value					
		Insulation								
		Resistance	Within the	e specified	initial value					





NO	ITE	М		PERFO	RMANCE	TEST CONDITION						
		Appearance	No mechanic	al damage sha	Il occur.	Temperature : 40±2 ℃						
				cteristics	Capacitance Change	Relative humidity : 90~95 %RH						
					Within ±5.0% or ±0.5pF	Duration time : 500 +12/-0 hr.						
			Cla	ss I	whichever is larger							
		Capacitance		A/VED)/	Willower is larger	Leave the capacitor in ambient						
		Capacitance	01	A(X5R)/ B(X7R)/	Within ±12.5%	condition for specified time* before						
			Class	X(X6S)	WILLIEF ±12.5%	measurement.						
			11		Within ±30%	CLASSI : 24±2 Hr.						
			F(Y5V)			CLASSII : 24±2 Hr.						
	Humidity	Q	Capacitance ≥ 30pF : Q≥ 350 10≤ Capacitance <30 pF : Q≥ 275 + 2.5×C									
13	(Steady	CLASS I	,		200 + 10×C (C: Capacitance)							
	State)			stic : A(X5R),	2. Characteristic : F(Y5V)							
	,			B(X7R)								
			0.05max (16)	` ′	0.075max (25V and over)							
		Tan δ	0.075max (10) ()	0.1max (16V, C<1.0µF)							
		CLASS II	0.075max	•	0.125max(16V, C≥ 1.0µF)							
		CLASS II	(6.3V excep	t Table 1)	0.15max (10V)							
			0.125max*		0.195max (6.3V)							
			(refer to Tab	le 1)								
		Insulation										
		Resistance	1,000 MΩ or	50M $\Omega\cdot\mu$ F whichev	ver is smaller.							
		Appearance	No mechanic	cal damage sha	Il occur.	Applied Voltage: rated voltage						
		Appearance		cteristics	Capacitance Change	Temperature : 40±2 °C						
			Onara		-	Humidity::90~95%RH						
		Capacitance		Cla	ss I	Within ±5.0% or ±0.5pF	Duration Time : 500 +12/-0 Hr.					
											I	whichever is larger
				A(X5R)/	Within ±12.5%	Perform the initial measurement according to						
				B(X7R)/	Within ±12.5%	Note1.						
				X(X6S)	Within ±30%							
			Class II		Within ±30%							
				F(Y5V)		Perform the final measurement according to						
					Within ±30%	Note2.						
	Moisture	Q	Capacitance	≥ 30pF : Q≥ 2	00							
14	Resistance	(Class I)	Capacitance	<30 pF : Q≥ 10	00 + 10/3×C (C: Capacitance)							
			1 Characteri	stic : A(X5R),	2. Characteristic : F(Y5V)							
			T. Onalacion	B(X7R)	2. Characteriolic : 1(101)							
			0.05max (16)		0.075max (25V and over)							
			0.075max (10	,	0.1max (16V, C<1.0µF)							
		^	0.075max	•	0.125max(16V, C≥ 1.0µF)							
		Tan δ	(6.3V excep	ot Table 1)	0.15max (10V)							
		(Class II)	0.125max*	,	0.195max (6.3V)							
			(refer to Tal	ble 1)								
				<u> </u>								
			X(X6S) 0.11r	max (6.3V and I	pelow)							
		Insulation	500 MΩ or 25	5MΩ·μF whicheve	r is smaller.							
		Resistance	300 mm 01 20	willGlieve	i io diffaliot.							





NO	ITE	М		PER	FORMANCE		TEST CONDIT	ION			
		Appearance	No mechanic	cal damage	shall occur.	'''	oltage: 200%* of the	•			
			Charact	eristics	Capacitance Change		ime: 1000 +48/-0 H	•			
					Within ±3% or ±0.3pF,	Charge/Dis	Charge/Discharge Current : 50m/ max.				
			Class	s I	Whichever is larger						
		Capacitance	A(X5R)/ B(X7R) Within ±12.5%		voltage	* refer to table(3) : 150%/100% of the rated voltage					
			Class II	X(X6S)	Within ±25%	Perform th	e initial measuremen	t according to			
					Within ±30%	Note1 for	Class II				
				F(Y5V)	Within ±30%						
			Capacitance	≥30pF : 0	⊋ ≥ 350	Perform th	e final measurement	according to			
		Q (Olara I)	10≤ Capaci	itance <30 p	$F : Q \ge 275 + 2.5 \times C$	Note2.	e ina measurement	according to			
	I EI-	(Class I)			≥ 200 +10×C (C: Capacitance)						
15	High		1. Character		R), 2. Characteristic : F(Y5V)						
15	Temperature Resistance			B(X7R							
	nesisiance		0.05max		0.075max						
		Tan δ (Class Π)	(16V and o	,	(25V and over)						
			0.075max (1	0V)	0.1max(16V, C<1.0μF)						
			0.075max		0.125max(16V, C≥1.0μF)						
			(6.3V excep	ot Table 1)	0.15max (10V)						
			0.125max*		0.195max (6.3V)						
			(refer to Ta	ble 1)							
			X(X6S) 0.11	max (6.3V a	and below)						
		Insulation Resistance	1,000 MΩ or	50 ΜΩ·μF w hi	chever is smaller.						
		Appearance	No mechanio	cal damage	shall occur.	Capacito	r shall be subjecte	d to 5 cycles.			
			Charact	eristics	Capacitance Change	Condition	for 1 cycle :				
			Class	s I	Within ±2.5% or ±0.25 pF	Step	Temp.(°C)	Time(min.)			
					Whichever is larger	_ 1	Min. operating	30			
		Capacitance		A(X5R)/	Within ±7.5%		temp.+0/-3				
	_		Class	B(X7R)/		2	25	2~3			
16	Temperature			X(X6S)	Within ±15%	3	Max. operating	30			
	Cycle			F(Y5V)	Within ±20%		temp.+3/-0				
		Q	Within the s	pecified initia	al value	4	25	2~3			
		(Class I)				_	e capacitor in amb				
		Tan δ	Within the s	pecified initis	al value	1	fied time* before m	neasurement			
		(Class II)	Within the specified initial value				* 24 ± 2 hours (Class I)				
		Insulation	Within the s	necified initia	al value	24 ± 2	hours (Class II)				
		Resistance		poonou millo							





		Reco	ommended Sold	ering Method				
		Size	Temperature	_	Condition			
		inch (mm)	Characteristic	Capacitance	Flow	Reflow		
		0201 (0603)	-	-	-	0		
		0402 (1005)						
		0603 (1608)	Class I	=	0	0		
			Class II	$C < 1\mu F$	0	0		
			Class II	C ≥ 1 μF	-	0		
	Recommended		Class I	-	0	0		
18	Soldering Method	0805 (2012)	Class II	C < 4.7μF	0	0		
	By Size & Capacitance		Class II	C ≥ 4.7 <i>µ</i> F	-	0		
	by 6126 a Sapasitarios		Array	-	-	0		
			Class I	-	0	0		
		1006 (2016)	Class II	C < 10μF	0	0		
		1206 (3216)	Class II	C ≥ 10 <i>µ</i> F	-	0		
			Array	-	-	0		
		1210 (3225)				0		
		1808 (4520)				0		
		1812 (4532)	_	-	-	0		
		2220 (5750)				0		

Note1. Initial Measurement For Class $\boldsymbol{\mathbb{I}}$

Perform the heat treatment at 150%+0/-10% for 1 hour. Then Leave the capacitor in ambient condition for 48 ± 4 hours before measurement. Then perform the measurement.

Note2. Latter Measurement

1. CLASS I

Leave the capacitor in ambient condition for 24±2 hours before measurement

Then perform the measurement.

2. Class ${\mathbb I}$

Perform the heat treatment at $150\,^{\circ}\text{C} + 0/-10\,^{\circ}\text{C}$ for 1 hour. Then Leave the capacitor in ambient condition for 48 ± 4 hours before measurement. Then perform the measurement.

*Table1.

Tan δ 0.125max* $0201 \ C \ge 0.022 \mu F$ $0402 \ C \ge 0.22 \mu F$ $0603 \ C \ge 2.2 \mu F$ $0805 \ C \ge 4.7 \mu F$ $1206 \ C \ge 10.0 \mu F$ $1210 \ C \ge 22.0 \mu F$ $1812 \ C \ge 47.0 \mu F$ $2220 \ C \ge 100.0 \mu F$ All Low Profile $Capacitors \ (P.16).$

*Table2.

High Tem	perature Resistance test
⊿C (Y5V)	± 30%
	0402 C ≥ 0.47 <i>μ</i> F
	0603 C ≥ 2.2μF
Class∏	0805 C ≥ 4.7μ F
F(Y5V)	1206 C ≥ 10.0 <i>μ</i> F
1(130)	1210 C ≥22.0 <i>µ</i> F
	1812 C ≥ 47.0 <i>μ</i> F
	2220 C $\geq 100.0 \mu \text{F}$

*Table3.

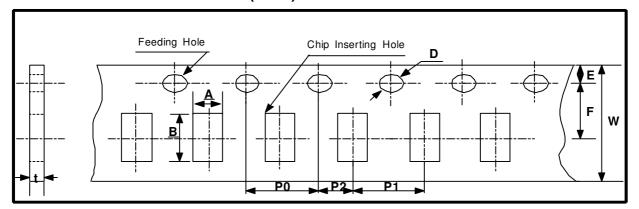
	High Temperature Resistance test											
Applied Voltage	100% of the rated voltage	150% of the rated voltage										
Class II A(X5R), B(X7R), X(X6S), F(Y5V)	0201 C $\geq 0.1 \mu F$ 0402 C $\geq 1.0 \mu F$ 0603 C $\geq 4.7 \mu F$ 0805 C $\geq 22.0 \mu F$ 1206 C $\geq 47.0 \mu F$ 1210 C $\geq 100.0 \mu F$ All Low Profile Capacitors (P.16).	0201 C $\geq 0.022 \mu F$ 0402 C $\geq 0.47 \mu F$ 0603 C $\geq 2.2 \mu F$ 0805 C $\geq 4.7 \mu F$ 1206 C $\geq 10.0 \mu F$ 1210 C $\geq 22.0 \mu F$ 1812 C $\geq 47.0 \mu F$ 2220 C $\geq 100.0 \mu F$										





PACKAGING

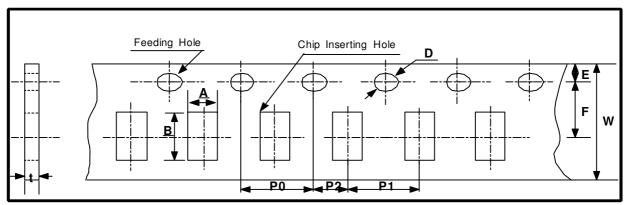
● CARDBOARD PAPER TAPE (4mm)



unit : mm

	mbol ype	Α	В	W	F	E	P1	P2	P0	D	t
D i m	0603 (1608)	1.1 ±0.2	1.9 ±0.2								
e n s	0805 (2012)	1.6 ±0.2	2.4 ±0.2	8.0 ±0.3	3.5 ±0.05	1.75 ±0.1	4.0 ±0.1	2.0 ±0.05	4.0 ±0.1	Ф1.5 +0.1/-0	1.1 Below
i o n	1206 (3216)	2.0 ±0.2	3.6 ±0.2								

● CARDBOARD PAPER TAPE (2mm)



unit: mm

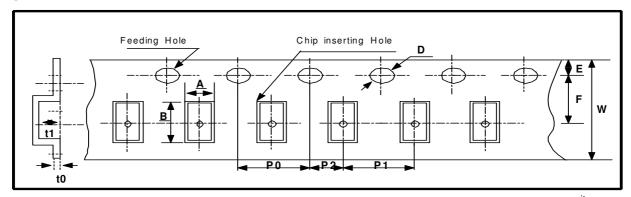
	Symbol Type	A	В	w	F	E	P1	P2	P0	D	t
D i m e	0201 (0603)	0.38 ±0.03	0.68 ±0.03	8.0	3.5	1.75	2.0	2.0	4.0	Ф1.5	0.37 ±0.03
n s i o n	0402 (1005)	0.62 ±0.04	1.12 ±0.04	±0.3	±0.05	±0.1	±0.05	±0.05	±0.1	+0.1/-0.03	0.6 ±0.05





PACKAGING

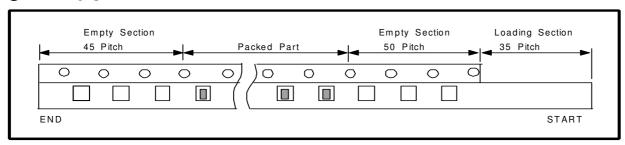
● EMBOSSED PLASTIC TAPE



unit: mm

Sy	m bol	Α	В	w	F	Е	P1	P2	P0	D	t1	t0
Т	ype			**	·	_		1 2				.0
	0805 (2012)	1.45 ±0.2	2.3 ±0.2									
P	1206 (3216)	1.9 ±0.2	3.5 ±0.2	8.0 ±0.3	3.5 ±0.05		4.0 ±0.1				2.5 max	
m e	1210 (3225)	2.9 ±0.2	3.7 ±0.2			1.75		2.0	4.0	Ф1.5 +0.1/-0		0.6
n s i	1808 (4520)	2.3 ±0.2	4.9 ±0.2			±0.1		±0.05	±0.1	+0.17-0		Below
o n	1812 (4532)	3.6 ±0.2	4.9 ±0.2	12.0 ±0.3	5.60 ±0.05		8.0 ±0.1				3.8 max	
	2220 (5750)	5.5 ±0.2	6.2 ±0.2									

TAPING SIZE



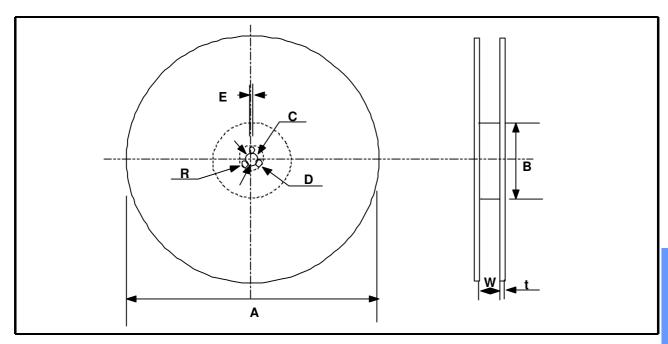
Type	Symbol	Size	Cardboard Paper Tape	Symbol	Size	Embossed Plastic Tape
		0201(0603)	10,000		All Size ≤3216 1210(3225),1808(4520) (t≤1.6mm)	2,000
7" Reel	С	0402(1005)	10,000	E	1210(3225)(t≥2.0mm)	1,000
		OTHERS	4,000		1808(4520)(t≥2.0 m m)	1,000
10" Reel	0	-	10,000	-	-	-
	D	0402(1005)	50,000	F	All Size ≤3216 1210(3225),1808(4520) (t<1.6mm)	10,000
		OTHERS	10,000		$1210(3225)(1.6 \le t < 2.0 \text{mm}) \\ 1206(3216)(1.6 \le t)$	8,000
13" Reel		0603(1608)	10,000 or 15,000		1210(3225),1808(4520) (t≥2.0mm)	4,000
	L	0805(2012) (t≤0.85 m m)	15,000 or 10,000(Option)		1812(4532)(t≤2.0 m m)	4,000
		1206(3216) (t≤0.85mm)	10,000		1812(4532)(t>2.0mm) 5750(2220)	2,000





PACKAGING

• REEL DIMENSION



unit : mm

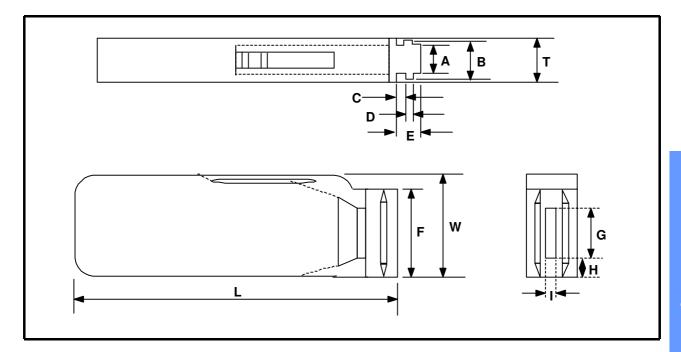
Symbol	Α	В	С	D	E	W	t	R
7" Reel	ф180+0/ -3	φ60+1/ -3		05 0.5	00105	0.14.5	1.2±0.2	1.0
13" Reel	ф330±2.0	ф80+1/ -3	φ13±0.3	25±0.5	2.0±0.5	9±1.5	2.2±0.2	1.0





BULK CASE PACKAGING

- Bulk case packaging can reduce the stock space and transportation costs.
- The bulk feeding system can increase the productivity.
- It can eliminate the components loss.



unit: mm

Symbol	Α	В	Т	С	D	E
Dimension	6.8±0.1	8.8±0.1	12±0.1	1.5+0.1/-0	2+0/-0.1	3.0+0.2/-0

Symbol	F	W	G	Н	L	I
Dimension	31.5+0.2/-0	36+0/-0.2	19±0.35	7±0.35	110±0.7	5±0.35

QUANTITY OF BULK CASE PACKAGING

unit : pcs

C:	0400(1005)	0000(1000)	0805(2012)		
Size	0402(1005)	0603(1608)	T=0.65mm	T=0.85mm	
Quantity	50,000	10,000 or 15,000	10,000	5,000 or 10,000	

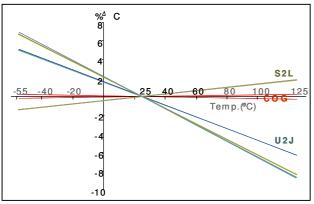


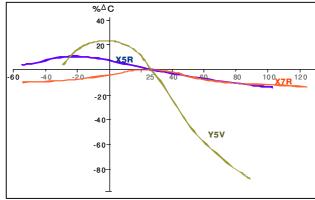


APPLICATION MANUAL

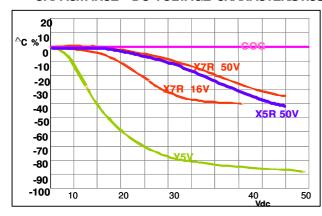
ELECTRICAL CHARACTERISTICS

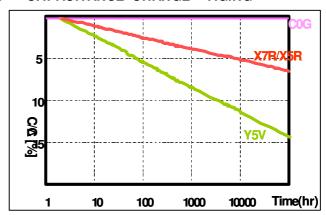
► CAPACITANCE - TEMPERATURE CHARACTERISTICS



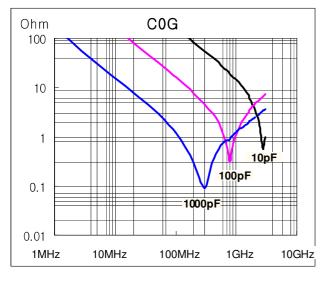


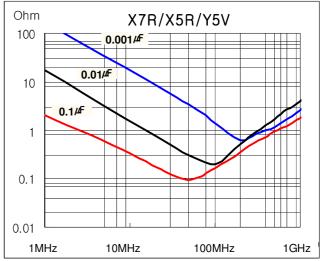
► CAPACITANCE - DC VOLTAGE CHARACTERISTICS ► CAPACITANCE CHANGE - AGING





► IMPEDANCE - FREQUENCY CHARACTERISTICS









STORAGE CONDITION

Storage Environment

The electrical characteristics of MLCCs were degraded by the environment of high temperature or humidity. Therefore, the MLCCs shall be stored in the ambient temperature and the relative humidity of less than 40 °C and 70%, respectively.

Guaranteed storage period is within 6 months from the outgoing date of delivery.

Corrosive Gases

Since the solderability of the end termination in MLCC was degraded by a chemical atmosphere such as chlorine, acid or sulfide gases, MLCCs must be avoid from these gases.

▶ Temperature Fluctuations

Since dew condensation may occur by the differences in temperature when the MLCCs are taken out of storage, it is important to maintain the temperature-controlled environment.

DESIGN OF LAND PATTERN

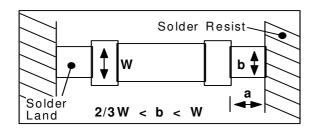
When designing printed circuit boards, the shape and size of the lands must allow for the proper amount of solder on the capacitor.

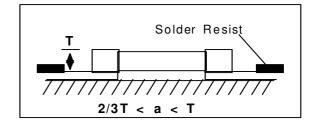
The amount of solder at the end terminations has a direct effect on the crack.

The crack in MLCC will be easily occurred by the tensile stress which was due to too much amount of solder. In contrast, if too little solder is applied, the termination strength will be insufficiently.

Use the following illustrations as guidelines for proper land design.

Recommendation of Land Shape and Size.









ADHESIVES

When flow soldering the MLCCs, apply the adhesive in accordance with the following conditions.

► Requirements for Adhesives

They must have enough adhesion, so that, the chips will not fall off or move during the handling of the circuit board.

They must maintain their adhesive strength when exposed to soldering temperature.

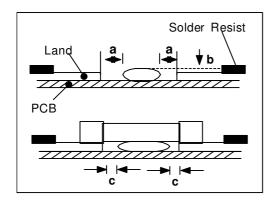
They should not spread or run when applied to the circuit board.

They should harden quickly. They should not corrode the circuit board or chip material.

They should be a good insulator. They should be non-toxic, and not produce harmful gases, nor be harmful when touched.

Application Method

It is important to use the proper amount of adhesive. Too little and much adhesive will cause poor adhesion and overflow into the land, respectively.



		unit : mm
Туре	21	31
а	0.2 min	0.2 min
b	70~100 µm	70~100 <i>μ</i> m
С	> 0	> 0

▶ Adhesive hardening Characteristics

To prevent oxidation of the terminations, the adhesive must harden at $160\,^{\circ}$ C or less, within 2 minutes or less.

MOUNTING

▶ Mounting Head Pressure

Excessive pressure will cause crack to MLCCs. The pressure of nozzle will be 300g maximum during mounting.

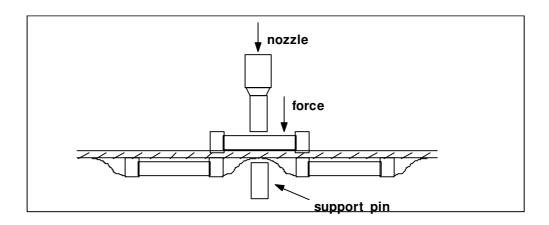




▶ Bending Stress

When double-sided circuit boards are used, MLCCs first are mounted and soldered onto one side of the board. When the MLCCs are mounted onto the other side,

it is important to support the board as shown in the illustration. If the circuit board is not supported, the crack occur to the ready-installed MLCCs by the bending stress.



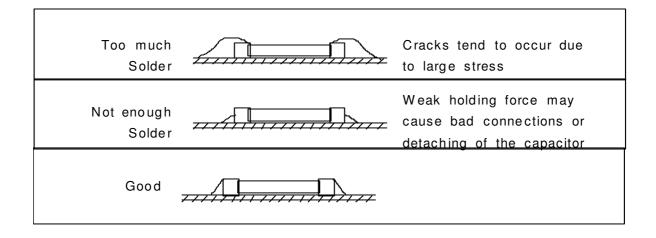
Manual Soldering

Manual soldering can pose a great risk of creating thermal cracks in chip capacitors.

The hot soldering iron tip comes into direct contact with the end terminations, and operator's carelessness may cause the tip of the soldering iron to come into direct contact with the ceramic body of the capacitor.

Therefore the soldering iron must be handled carefully, and close attention must be paid to the selection of the soldering iron tip and to temperature control of the tip.

Amount of Solder







▶ Cooling

Natural cooling using air is recommended. If the chips are dipped into solvent for cleaning, the temperature difference($\triangle T$) must be less than 100 $^{\circ}$ C

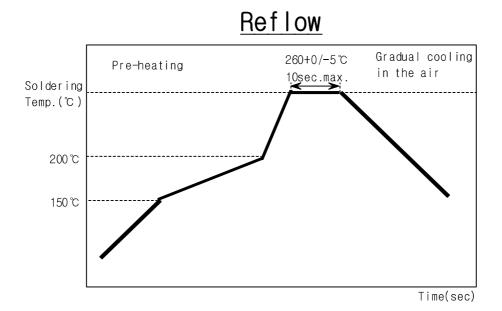
▶ Cleaning

If rosin flux is used, cleaning usually is unnecessary. When strongly activated flux is used, chlorine in the flux may dissolve into some types of cleaning fluids, thereby affecting the chip capacitors. This means that the cleaning fluid must be carefully selected, and should always be new.

▶ Notes for Separating Multiple, Shared PC Boards.

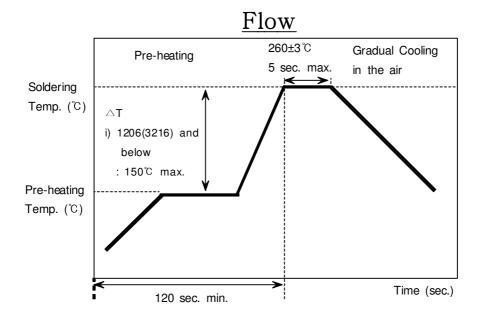
A multi-PC board is separated into many individual circuit boards after soldering has been completed. If the board is bent or distorted at the time of separation, cracks may occur in the chip capacitors. Carefully choose a separation method that minimizes the bending often circuit board.

► Recommended Soldering Profile









Soldering Iron

Variation of Temp.	Soldering	Pre-heating	Soldering	Cooling
variation of Temp.	Temp (℃)	Time (Sec)	Time(Sec)	Time(Sec)
△T≤130	300±10℃max	≥ 60	≤ 4	-

Condition of Iron facilities				
Wattage	Tip Diameter	Soldering Time		
20W Max	3mm Max	4 Sec Max		

^{*} Caution - Iron Tip Should Not Contact With Ceramic Body Directly.